xxxFN (JEDEC SOP) is not available in

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC164F,TC74VHC164FN,TC74VHC164FT,TC74VHC164FK

Note:

8-Bit Shift Register (S-IN, P-OUT)

The TC74VHC164 is an advanced high speed CMOS 8-BIT SERIAL-IN PARALLEL-OUT SHIFT REGISTER fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of a serial-in, parallel-out 8-bit shift register with a CLOCK input and an overriding $\overline{\text{CLEAR}}$ input.

Two serial data inputs (A, B) are provided so that one may be used as a data enable.

An input protection circuit ensures that 0 to 5.5~V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 to 3~V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: $f_{max} = 175 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- · Power down protection is provided on all inputs.
- Balanced propagation delays: t_{pLH} ≃ t_{pHL}
- Wide operating voltage range: V_{CC} (opr) = 2 to 5.5 V
- Low noise: VOLP = 0.8 V (max)
- · Pin and function compatible with 74ALS164

Japan. TC74VHC164F SOP14-P-300-1.27A TC74VHC164FN SOL14-P-150-1.27 TC74VHC164FT TSSOP14-P-0044-0.65A TC74VHC164FK

Weiaht

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 SOP14-P-300-1.27A
 : 0.18 g (typ.)

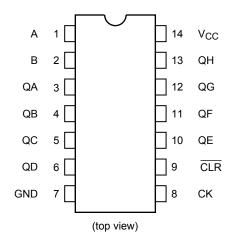
 SOL14-P-150-1.27
 : 0.12 g (typ.)

 TSSOP14-P-0044-0.65A
 : 0.06 g (typ.)

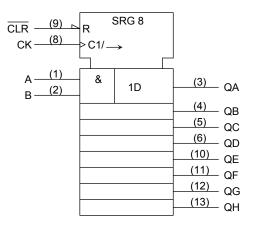
 VSSOP14-P-0030-0.50
 : 0.02 g (typ.)

VSSOP14-P-0030-0.50

Pin Assignment



IEC Logic Symbol



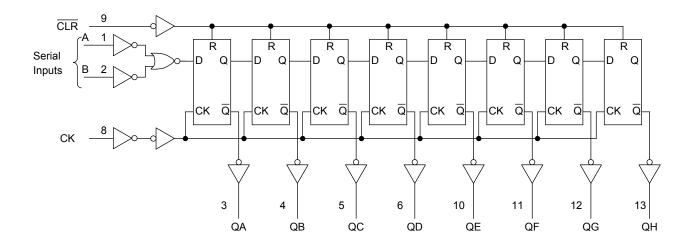
Truth Table

	Inp	uts		Outputs					
CLR	CK	Serial IN		04	0		OH		
CLR	CK A B QA		QA	QB		QH			
L	Х	Х	Х	L	L		L		
Н	\neg	Х	Х	No Change					
Н		L	Х	L	QAn		QG _n		
Н		Х	L	L	QA _n		QG _n		
Н		Н	Н	Н	QA _n		QG _n		

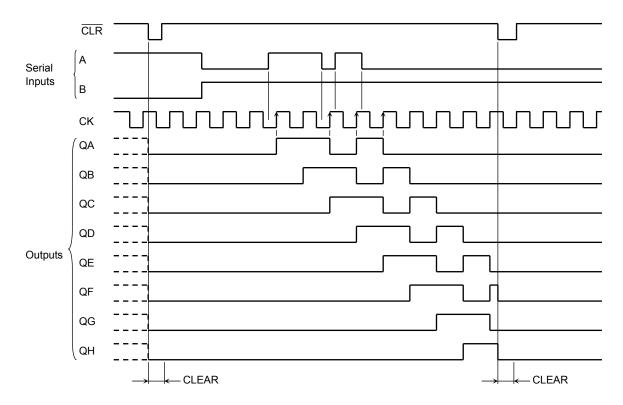
X: Don't care

QAn to QGn: The level of QA to QG, respectively, before the most recent positive edge of the clock.

System Diagram



Timing Chart



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	lık	-20	mA
Output diode current	Гок	±20	mA
DC output current	Гоит	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

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Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0 to 5.5	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	T _{opr}	−40 to 85	°C	
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V)	ne/\/	
input rise and rail time	uvuv	0 to 20 (V _{CC} = 5 ± 0.5 V)	ns/V	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			7	「a = 25°(Ta = -40 to 85°C		Unit
Sharadioneside	Cynnon.			V _{CC} (V)	Min	Тур.	Max	Min	Max	
High-level input voltage	V _{IH}	_			1.50 V _{CC} × 0.7		-	1.50 V _{CC} × 0.7	-	V
Low-level input voltage	V _{IL}	_		2.0 3.0 to 5.5	_ _	_ _	0.50 V _{CC} × 0.3	_ _	0.50 V _{CC} × 0.3	V
High-level output voltage	Voн	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA I _{OH} = -4 mA	2.0 3.0 4.5 3.0	1.9 2.9 4.4 2.58	2.0 3.0 4.5	_ _ _ _	1.9 2.9 4.4 2.48	_ _ _ _	٧
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I_{OL} = -8 mA I_{OL} = 50 μ A I_{OL} = 4 mA I_{OL} = 8 mA	4.5 2.0 3.0 4.5 3.0 4.5	3.94	0.0 0.0 0.0	0.1 0.1 0.1 0.36 0.36	3.80	0.1 0.1 0.1 0.44 0.44	V
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _C	V _{IN} = V _{CC} or GND		_	_	4.0	_	40.0	μΑ



Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	est Condition		Ta = 25°C		Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	t _{w (L)}		3.3 ± 0.3	_	5.0	5.0	no
(CK)	t _{w (H)}	_	5.0 ± 0.5	_	5.0	5.0	ns
Minimum pulse width	4		3.3 ± 0.3	_	5.0	5.0	20
(CLR)	t _{w (L)}	_	5.0 ± 0.5	_	5.0	5.0	ns
Minimum and undiman			3.3 ± 0.3	_	5.0	6.0	ns
Minimum set-up time	t _S	_	5.0 ± 0.5	_	4.5	4.5	
Minimo una la alal tima a			3.3 ± 0.3	_	0.0	0.0	
Minimum hold time	t _h	_	5.0 ± 0.5	_	1.0	1.0	ns
Minimum removal time	4		3.3 ± 0.3	_	2.5	2.5	
(CLR)	t _{rem}	_	5.0 ± 0.5	-	2.5	2.5	ns

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Tes	Test Condition			Ta = 25°C			Ta = −40 to 85°C	
	- ,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			3.3 ± 0.3	15	_	8.4	12.8	1.0	15.0	
Propagation delay time	t _{pLH}		3.5 1 0.5	50	_	10.9	16.3	1.0	18.5	ns
(CK-Q)	t_{pHL}	_	5.0 ± 0.5	15	_	5.8	9.0	1.0	10.5	113
			3.0 ± 0.3	50	_	7.3	11.0	1.0	12.5	
	t _{pHL}	_	3.3 ± 0.3	15	_	8.3	12.8	1.0	15.0	ns MHz
Propagation delay time				50	_	10.8	16.3	1.0	18.5	
(CLR -Q)			5.0 ± 0.5	15	_	5.2	8.6	1.0	10.0	
				50	_	6.7	10.6	1.0	12.0	
	f _{max}		3.3 ± 0.3	15	80	125	_	65	_	
Maximum clock		_		50	50	75	_	45	_	
frequency			5.0 ± 0.5	15	125	175	_	105	_	
				50	85	115	_	75	_	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note)	_	76	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

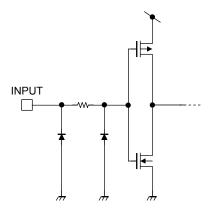
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta =	- Unit	
Characteristics	Syllibol		V _{CC} (V)	Тур.	Max	Oill
Quiet output maximum dynamic V_{OL}	V_{OLP}	C _L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V

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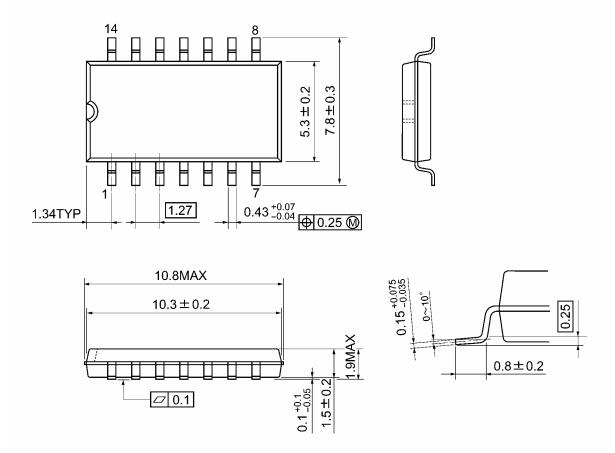
Input Equivalent Circuit



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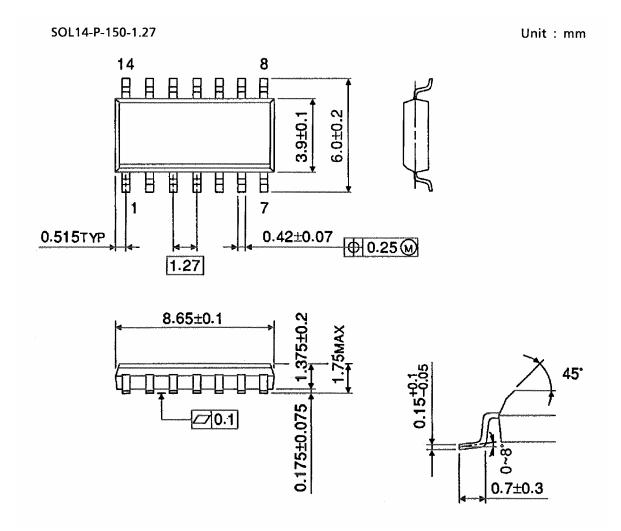
Package Dimensions

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A Unit: mm 6.4 ± 0.2 $0.22^{+0.09}_{-0.06}$ 0.65 0.55TYP **⊕**0.13**M** 5.4MAX 5.0±0.1 0~10 0.25 1.0±0.05 0.1±0.05 S Ø.1S (0.5)

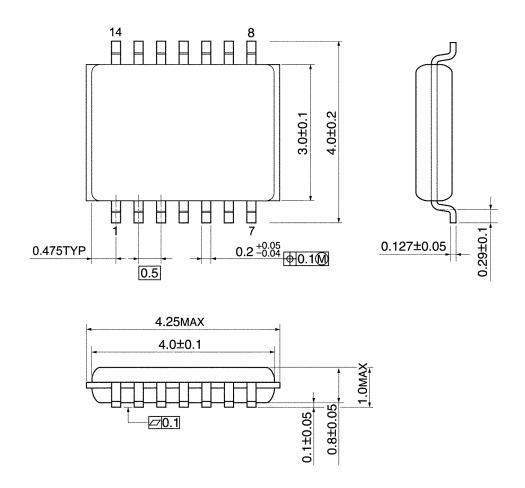
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Weight: 0.06 g (typ.)

0.45~0.75

Package Dimensions

VSSOP14-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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